TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX573F TC74LCX573FK

Low-Voltage Octal D-Type Latch with 5-V Tolerant Inputs and Outputs

The TC74LCX573 is a high-performance CMOS octal D-type latch. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage $(3.3 \text{ V}) \text{ V}_{CC}$ applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

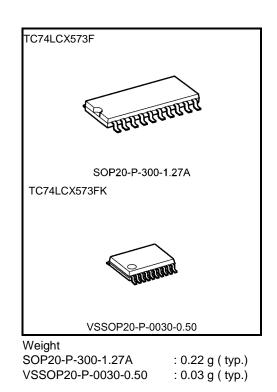
This 8-bit D-type latch is controlled by a latch enable input (LE) and an output enable input (\overline{OE}).

When the \overline{OE} input is high, the eight outputs are in a high-impedance state.

All inputs are equipped with protection circuits against static discharge.

Features

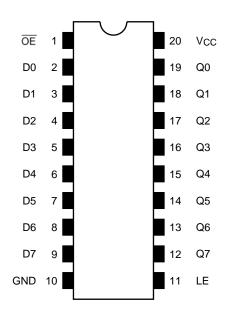
- Low-voltage operation: VCC = 1.65 to 3.6 V
- High-speed operation: $t_{pd} = 8.0 \text{ ns} \text{ (max)} (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA} (\text{min}) (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: > ±500 mA
- Available in JEITA SOP, VSSOP (US)
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 573 type



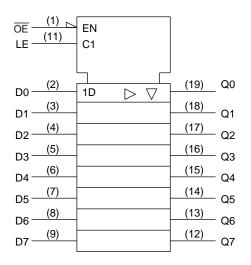
Note: The Electrical Characteristics of V_{CC} = 1.8 ± 0.15 V is only applicable for products which manufactured from January 2009 onward.

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Pin Assignment (top view)



IEC Logic Symbol



Truth Table

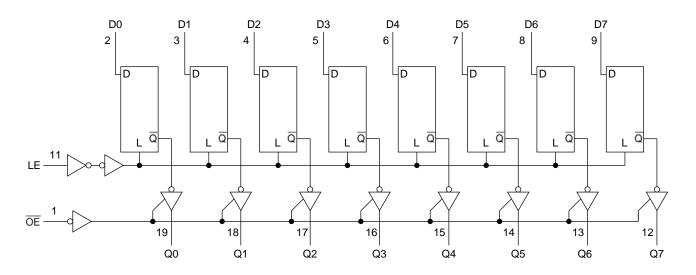
	Outpute		
ŌĒ	LE	D	Outputs
Н	Х	Х	Z
L	L	Х	Qn
L	Н	L	L
L	Н	Н	Н

X: Don't care

Z: High impedance

Qn: Q outputs are latched at the time when the LE input is taken to a low logic level.

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	Vcc	-0.5 to 7.0	V
DC input voltage	Vin	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 2)	
DC output voltage	Vout	–0.5 to V _{CC} + 0.5 (Note 3)	V
Input diode current	liк	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	IOUT	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	ICC/IGND	±100	mA
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 2: Output in OFF state
- Note 3: High or low state. IOUT absolute maximum rating must be observed.
- Note 4: VOUT < GND, VOUT > VCC

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit	
Deview eventhe visite en	Maa	1.65 to 3.6		
Power supply voltage	Vcc	1.5 to 3.6 (Note 2)	V	
Input voltage	Vin	0 to 5.5	V	
Output veltage	Vout	0 to 5.5 (Note 3)	V	
Output voltage		0 to VCC (Note 4)		
Output ourroat		±24 (Note 5)	~ ^	
Output current	IOH/IOL	±12 (Note 6)	mA	
Operating temperature	Topr	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 2: Data retention only

Note 3: Output in OFF state

Note 4: High or low state

Note 5: VCC = 3.0 to 3.6 V

Note 6: VCC = 2.7 to 3.0 V

Note 7: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85° C)

Characteristi	Symbol	Symbol Test Condition			Min	Max	Unit	
Characteristi	165	Symbol	Vcc (V)		IVIIII	IVIAX	Unit	
					1.65 to 2.3	Vcc×0.9	_	
	H-level	VIH	_	_		1.7	—	
					2.7 to 3.6	2.0	—	V
Input voltage					1.65 to 2.3	—	Vcc × 0.1	
	L-level	VIL	_	-	2.3 to 2.7	—	0.7	
					2.7 to 3.6	_	0.8	
				IOH = -100 μA	1.65 to 3.6	Vcc-0.2	—	
				I _{OH} = -4 mA	1.65	1.05	—	
		Maria		I _{OH} = -8 mA	2.3	1.7	_	- V
	H-level	Vон	$V_{IN} = V_{IH} \text{ or } V_{IL}$	Iон = -12 mA	2.7	2.2	_	
				I _{OH} = -18 mA	3.0	2.4	_	
Output upltage				Iон = -24 mA	3.0	2.2	_	
Output voltage			VIN = VIH or VIL	I _{OL} = 100 μA	1.65 to 3.6	_	0.2	
				$I_{OL} = 4 \text{ mA}$	1.65	_	0.45	
	1.1			IOL = 8 mA	2.3		0.7	
	L-level	Vol		I _{OL} = 12 mA	2.7		0.4	
				I _{OL} = 16 mA	3.0		0.4	
				I _{OL} = 24 mA	3.0		0.55	
Input leakage current		l _{IN}	V _{IN} = 0 to 5.5 V		1.65 to 3.6		±5.0	μA
3-state output OFF state current		loz	VIN = VIH or VIL VOUT = 0 to 5.5 V		1.65 to 3.6	_	±5.0	μΑ
Power-off leakage current		IOFF	V _{IN} /V _{OUT} = 5.5 V		0		10.0	μA
			VIN = VCC or GND		1.65 to 3.6		10.0	
Quiescent supply curre	ent	Icc	VIN/VOUT = 3.6 to 5.5 V		1.65 to 3.6		±10.0	μA
Increase in ICC per inp	ut	∆lcc	VIH = VCC - 0.6 V	(per 1 input)	2.7 to 3.6	_	500	

AC Characteristics (Ta = -40 to 85° C)

Characteristics	Symbol	Test Condition		Min	Max	Unit
			V _{CC} (V)			
			1.8 ± 0.15		30.0	ns
Propagation delay time	tpLH	Figure 1, Figure 2	2.5 ± 0.2	—	10.0	
(D-Q)	tpHL		2.7	—	9.0	
			$\textbf{3.3}\pm\textbf{0.3}$	1.5	8.0	
			$\textbf{1.8}\pm\textbf{0.15}$	_	30.0	
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.5 ± 0.2	_	10.5	ns
(LE-Q)	t _{pHL}		2.7	—	9.5	
			$\textbf{3.3}\pm\textbf{0.3}$	1.5	8.5	
			1.8 ± 0.15	_	34.0	
Output enable time	tpZL	Figure 1, Figure 3	2.5 ± 0.2		17.0	ns
	tpZH	Figure 1, Figure 3	2.7	_	9.5	ns
			$\textbf{3.3}\pm\textbf{0.3}$	1.5	8.5	
			1.8±0.15		28.0	
Output disable time	tpLZ tpHZ	Figure 1, Figure 3	2.5±0.2	_	14.0	ns
Output disable time			2.7		7.0	
			$\textbf{3.3}\pm\textbf{0.3}$	1.5	6.5	
		Figure 1, Figure 2	1.8 ± 0.15	10.0	_	- ns
Minimum pulse width			2.5 ± 0.2	5.0	_	
(LE)	t _w (H)		2.7	3.3		
			$\textbf{3.3}\pm\textbf{0.3}$	3.3	_	
			1.8 ± 0.15	10.0	_	ns
			2.5 ± 0.2	5.0	_	
Minimum setup time	ts	Figure 1, Figure 2	2.7	2.5	_	
			$\textbf{3.3}\pm\textbf{0.3}$	2.5	_	
Minimum hold time			1.8 ± 0.15	1.5	_	
			$\textbf{2.5}\pm\textbf{0.2}$	1.5	_	
	th	Figure 1, Figure 2	2.7	1.5	_	ns
			$\textbf{3.3}\pm\textbf{0.3}$	1.5	_	
	t _{osLH}		2.7	_	_	
Output to output skew	t _{osHL}	(Note)	$\textbf{3.3}\pm\textbf{0.3}$	_	1.0	ns

Note: Parameter guaranteed by design.

 $(\mathsf{tosLH} = |\mathsf{tpLHm} - \mathsf{tpLHn}|, \, \mathsf{tosHL} = |\mathsf{tpHLm} - \mathsf{tpHLn}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: tr = tf = 2.5 ns, CL = 50 pF, RL = 500 Ω)

Characteristics	Symbol	Test Condition	Vcc (V)	Тур.	Unit
Quiet output maximum dynamic VOL	VOLP	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V
Quiet output minimum dynamic VOL	Volv	$V_{IH}=3.3~V,~V_{IL}=0~V$	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

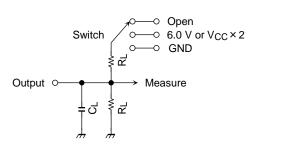
Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	CIN	—	3.3	7	pF
Output capacitance	Соит	_	3.3	8	pF
Power dissipation capacitance	Cpd	f _{IN} = 10 MHz (No	e) 3.3	25	pF

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $\label{eq:lcc} \text{ICC (opr)} = \text{CPD} \boldsymbol{\cdot} \text{VCC} \boldsymbol{\cdot} \text{fIN} + \text{ICC/8 (per bit)}$

AC Test Circuit

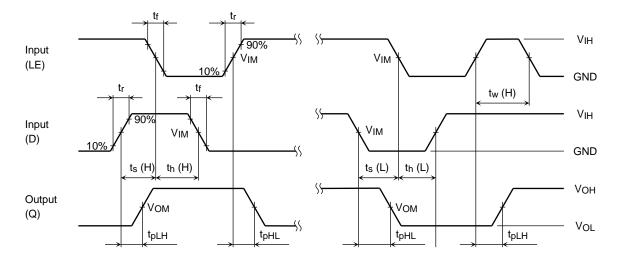


Parameter	Switch			
t _{pLH} , t _{pHL}	Open			
tpLZ, tpZL	6.0 V @ V _{CC} =3.3±0.3V @ V _{CC} =2.7V			
	V _{CC} ×2 @ V _{CC} =2.5±0.2V @ V _{CC} =1.8±0.15V			
tpHZ, tpZH	GND			

Figure 1

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AC Waveform



 $\label{eq:Figure 2} \quad t_{pLH}, \, t_{pHL}, \, t_w, \, t_s, \, t_h$

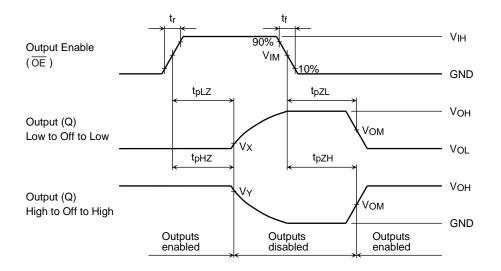


Figure 3 $t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}$

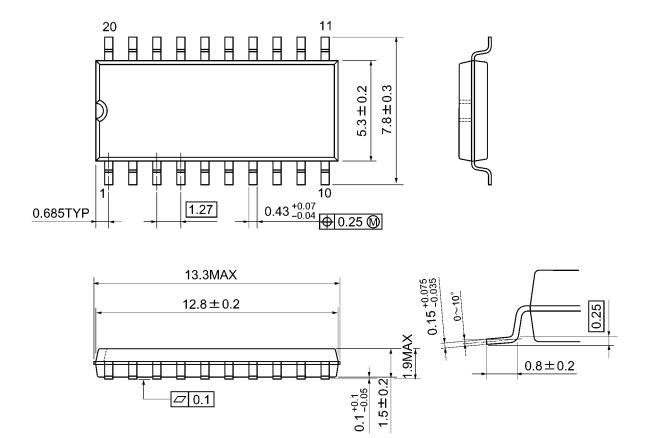
			V _{CC}	
Symbol		3.3 ± 0.3 V 2.7 V	$2.5\pm0.2\;V$	$1.8\pm0.15~V$
Input	VIH	2.7 V	V _{CC}	V _{CC}
	VIM	1.5 V	V _{CC} /2	V _{CC} /2
	tr,tf	2.5 ns	2.0 ns	2.0 ns
Output	Vом	1.5 V	V _{OH} /2	V _{OH} /2
	Vx	V _{OL} +0.3 V	VoL +0.15 V	VoL +0.15 V
	Vy	Voн -0.3 V	Voн -0.15 V	V _{OH} -0.15 V
Load	CL	50 pF	30 pF	30 pF
	RL	500 Ω	500 Ω	1 kΩ



Package Dimensions

SOP20-P-300-1.27A

Unit: mm



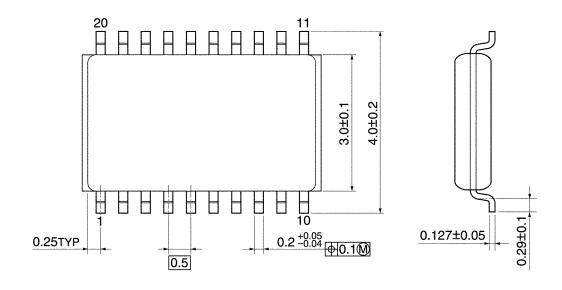
Weight: 0.22 g (typ.)

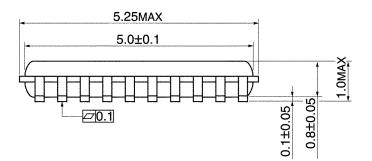


Package Dimensions

VSSOP20-P-0030-0.50

Unit: mm





Weight: 0.03 g (typ.)

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